

IXTY48P05T-TRL-VB Datasheet

Single-P Trench TO252 -60V MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A)		
- 60	0.020 at V _{GS} = - 10 V	- 50		
- 00	0.025 at V _{GS} = - 4.5 V	- 45		

FEATURES

- TrenchFET[®] Power MOSFET
- Material categorization:

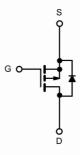


D G S Top View

TO-252

APPLICATIONS

· Load Switch



P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T _A = 28	5 °C, unless othe	rwise noted)			
Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V _{DS}	- 60	v	
Gate-Source Voltage		V _{GS}	± 20		
Continuous Drain Current (T ₁ = 175 °C)	T _C = 25 °C				
	T _C = 125 °C	טי	- 40	A	
Pulsed Drain Current		I _{DM}	- 160		
Avalanche Current		I _{AS}	- 50		
Single Pulse Avalanche Energy ^a	L = 0.1 mH	E _{AS}	125	mJ	
Power Dissipation	T _C = 25 °C	PD	113 ^c	113 ^c W	
	T _A = 25 °C	'D	2.5 ^{b, c}	VV	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150	°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
hundien te Anchient	t ≤ 10 s	R _{thJA}	15	18	
Junction-to-Ambient ^D	Steady State	NthJA	40	50	°C/W
Junction-to-Case		R _{thJC}	0.82	1.1	

Notes:

a. Duty cycle \leq 1 %.

b. When mounted on 1" square PCB (FR-4 material).
c. See SOA curve for voltage derating.
d. Package limited.

Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static		· · · · · ·					
Drain-Source Breakdown Voltage	V _{DS}	V _{GS} = 0 V, I _D = - 250 μA	- 60			V	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$	- 1.5		- 3	v	
Gate-Body Leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 20 V			± 100	nA	
		V _{DS} = - 60 V, V _{GS} = 0 V			- 1		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = - 60 V, V _{GS} = 0 V, T _J = 125 °C			- 50	μA	
		V_{DS} = - 60 V, V_{GS} = 0 V, T_{J} = 150 °C			- 100	2	
On-State Drain Current ^a	I _{D(on)}	V _{DS} = - 5 V, V _{GS} = - 10 V	- 50			А	
		V _{GS} = - 10 V, I _D = - 17 A		0.020		- Ω	
		V _{GS} = - 10 V, I _D = - 40 A, T _J = 125 °C		0.030			
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 10 V, I _D = - 40 A, T _J = 150 °C		0.035			
		V _{GS} = - 4.5 V, I _D = - 14 A		0.025			
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 15 V, I _D = - 17 A		61		S	
Dynamic ^b	•	· · · · · ·					
Input Capacitance	C _{iss}			2950			
Output Capacitance	C _{oss}	V _{GS} = 0 V, V _{DS} = - 25 V, f = 1 MHz		380		pF	
Reverse Transfer Capacitance	C _{rss}			305		P	
Total Gate Charge ^c	Qg			110	165		
Gate-Source Charge ^c	Q _{gs}	V _{DS} = - 30 V, V _{GS} = - 10 V, I _D = - 40 A		19		nC	
Gate-Drain Charge ^c	Q _{gd}			28			
Turn-On Delay Time ^c	t _{d(on)}			15	23	- ns	
Rise Time ^c	t _r	V _{DD} = - 30 V, R _L = 0.6 Ω		70	105		
Turn-Off Delay Time ^c	t _{d(off)}	$I_{D} \cong -40 \text{ A}, V_{GEN} = -10 \text{ V}, \text{ R}_{G} = 6$		175	260		
Fall Time ^c	t _f	Ω		175	260		
Source-Drain Diode Ratings and Cha	racteristics	$T_{\rm C} = 25 ^{\circ}{\rm C}^{\rm b}$					
Continuous Current	I _S				- 40	٨	
Pulsed Current	I _{SM}				- 80	A	
Forward Voltage ^a	V _{SD}	I _F = - 40 A, V _{GS} = 0 V		- 1	- 1.6	V	
Reverse Recovery Time	t _{rr}	I _F = - 40 A, dI/dt = 100 A/μs		45	70	ns	

Notes:

a. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %.
b. Guaranteed by design, not subject to production testing.
c. Independent of operating temperature.

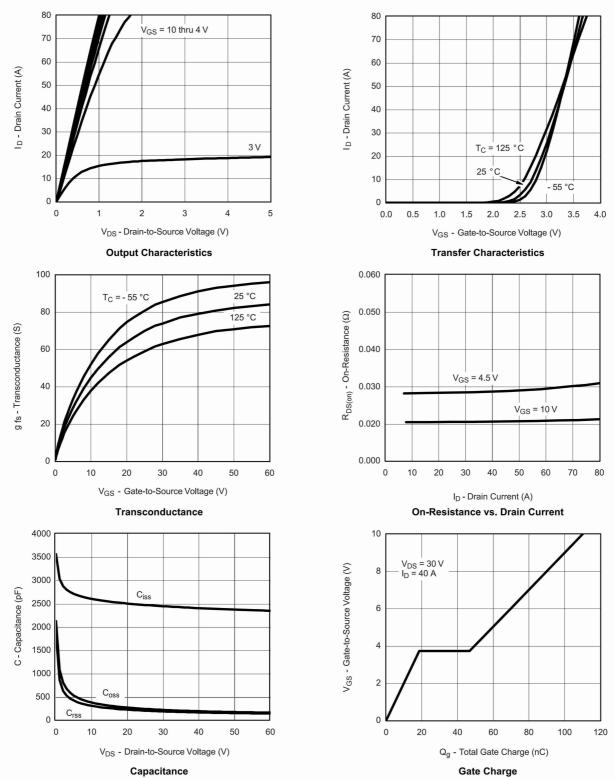
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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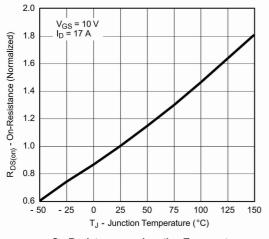


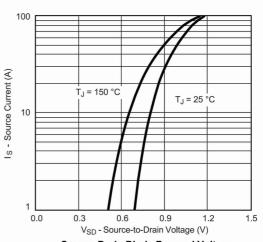
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



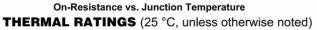
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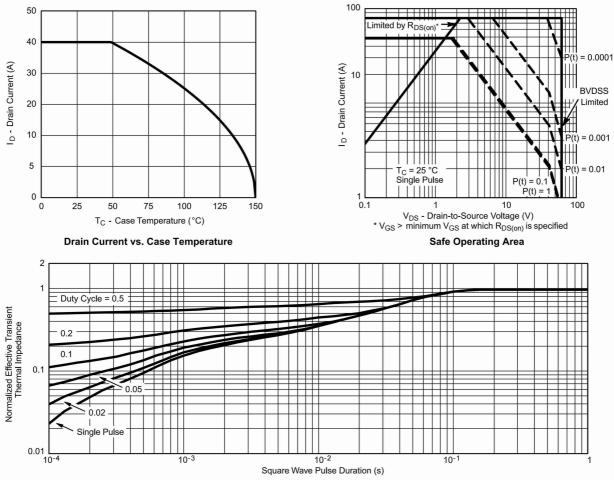






Source-Drain Diode Forward Voltage

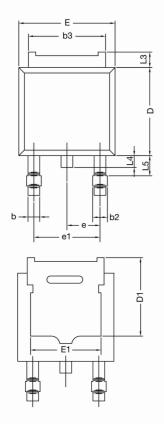


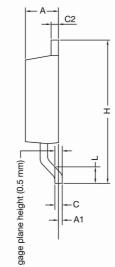






TO-252AA CASE OUTLINE





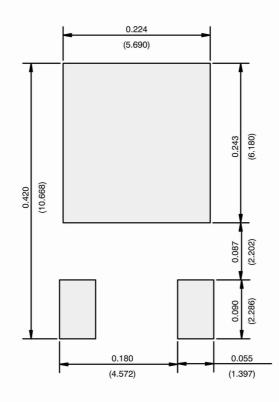
	MILLIN	IETERS	INCHES		
DIM.	MIN.	MAX.	MIN.	MAX.	
А	2.18	2.38	0.086	0.094	
A1	-	0.127	-	0.005	
b	0.64	0.88	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	
С	0.46	0.61	0.018	0.024	
C2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	
D1	5.21	-	0.205	-	
Е	6.35	6.73	0.250	0.265	
E1	4.32	-	0.170	-	
Н	9.40	10.41	0.370	0.410	
е	2.28	BSC	0.090 BSC		
e1	4.56	BSC	0.180 BSC		
L	1.40	1.78	0.055	0.070	
L3	0.89	1.27	0.035 0.0		
L4	-	1.02	-	0.040	
L5	1.14	1.52	0.045	0.060	
ECN: X12 DWG: 534	-0247-Rev. M, 7	24-Dec-12			

Note

• Dimension L3 is for reference only.



RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads Dimensions in Inches/(mm)



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